

## **TPS62366 Thermal and Device Lifetime Information**

---

Andreas Schaefer and Yann Ducommun

DC-DC Converters

### **ABSTRACT**

Wafer-level chip-scale packaging (WCSP) technologies have become one of the industry's leading packaging processes, meeting the continuous trend towards higher performance, smaller size microelectronics devices. As the power density in the devices increases and thermal dissipation turns into a challenge, chip manufacturers must pay special attention to potential reliability constraints, such as electromigration in the flip-chip solder bumps and under-bump metallization (UBM).

Electromigration is described as the diffusive transport of material in a conductor under the influence of electric current. This material flux leads to the formation of regions of mass depletion (voids) or accumulation (hillocks) in the conductor, eventually resulting in electrical failure of the interconnect. Electromigration is a fundamental physical response to the passage of electric current through a conductor and is not specific to a certain device type or manufacturing process.

Local temperature and current density are the dominating factors influencing electromigration and subsequent failure. Black's equation [1, 2] is successfully used as an empirical model estimating the mean time to failure (MTTF) of an interconnect taking electromigration into account:

$$\text{MTTF} \propto (J^{-n}) \exp(E_a/kT)$$

where  $J$  is the current density,  $E_a$  is the diffusion activation energy,  $k$  is the Boltzmann's constant,  $T$  is the temperature and  $n$  is a scaling factor.

Electromigration in flip-chip systems and its associated failure mechanisms were the subject of intense research in the last decade. For an overview, please refer to [3-13]

In this note, we investigate and quantify the potential reliability impact of electromigration of wafer-level chip-scale packages, taking Texas Instrument's TPS62366x (4-A peak output current) DC/DC converter family as an example. Measured efficiency and thermal data were used to derive the junction temperature,  $T_J$ , at specific ( $T_{\text{BOARD}}$ ,  $V_{\text{IN}}$ ,  $V_{\text{OUT}}$ ,  $I_{\text{OUT,AVE}}$ ) operating conditions and compute the expected resulting lifetime by means of a Black's equation. The results show that no significant electromigration-induced lifetime degradation is expected outside of the extreme corners of continuous operating conditions ( $T_{\text{BOARD}} = 85^\circ\text{C}$  with  $I_{\text{OUT,AVE}} > 2.5$  A and large  $V_{\text{OUT}}/V_{\text{IN}}$  duty cycles).

## Contents

<b>Background</b> .....	<b>2</b>
<b>TPS62366x Lifetime at Example Use Cases</b> .....	<b>2</b>
Current Density per Ball .....	2
Junction Temperature .....	2
Lifetime Estimation and Use Case Assumptions.....	3
Results and Discussion .....	3
PCB Layout Recommendations .....	4
<b>Conclusion</b> .....	<b>5</b>
References .....	5

## Figures

<b>Figure 1. Lifetime for <math>V_{OUT} = 1.0\text{ V}</math>, <math>T_{BOARD} = 65^{\circ}\text{C}</math></b> .....	<b>3</b>
<b>Figure 2. Lifetime for <math>V_{OUT} = 1.0\text{ V}</math>, <math>T_{BOARD} = 85^{\circ}\text{C}</math></b> .....	<b>3</b>
<b>Figure 3. Lifetime for <math>V_{OUT} = 1.2\text{ V}</math>, <math>T_{BOARD} = 65^{\circ}\text{C}</math></b> .....	<b>4</b>
<b>Figure 4. Lifetime for <math>V_{OUT} = 1.2\text{ V}</math>, <math>T_{BOARD} = 85^{\circ}\text{C}</math></b> .....	<b>4</b>

## Background

TI's specification for the reliability of the TPS62366xYZH WCSP package (16 bumps, 0.5 mm pitch, 245  $\mu\text{m}$  UBM diameter) is 100 k power-on-hours at  $T_J = 105^{\circ}\text{C}$ . This specification is fulfilled by the average current of the current waveform not exceeding  $I_{AVE} = 1.275\text{ A/pin}$ . Continuously exceeding  $I_{AVE} = 1.275\text{ A/pin}$  and/or  $T_J = 105^{\circ}\text{C}$  might affect the device reliability from electromigration. The next section investigates this impact by concentrating on TPS62366x example use cases.

## TPS62366x Lifetime at Example Use Cases

When quantifying the potential effects of electromigration on the TPS62366x lifetime for a given operating point, the current density per ball, as well as the junction temperature, needs to be estimated at those operating conditions.

### Current Density per Ball

In the TPS62366x converter family, the two SW balls carrying the output current are the relevant factor limiting electromigration-induced reliability performance at any ( $V_{IN}, V_{OUT}, I_{OUT}$ ) operating point. Each SW ball will carry an average output current of  $I_{OUT}/2$ , which can amount to 2-A peak for  $I_{OUT,PEAK} = 4\text{ A}$ . Considering an UBM opening diameter of 245  $\mu\text{m}$ , the peak current density per ball reaches  $J_{PEAK} \sim 4\text{ kA/cm}^2$  at  $I_{OUT,PEAK}$ .

### Junction Temperature

The junction temperature  $T_J$  is calculated as a function of the board temperature  $T_{BOARD}$  and the power  $P_{LOSS}$  dissipated by the converter:

$$T_J = T_{BOARD} + \theta_{JB} \times P_{LOSS}$$

where  $\theta_{JB} = 30^{\circ}\text{C}/\text{W}$  is the junction-to-board thermal resistance as measured using our reference evaluation board.

$P_{\text{LOSS}}$  is estimated using the measured TPS62366x efficiency  $\eta$  at the specific  $(V_{\text{IN}}, V_{\text{OUT}}, I_{\text{OUT}})$  operating point:

$$P_{\text{LOSS}} = I_{\text{OUT}} \times V_{\text{OUT}} (1/\eta - 1) - P_{\text{LOSS,INDUCTOR}}$$

with  $P_{\text{LOSS,INDUCTOR}}$  being the power dissipated in the inductor:

$$P_{\text{LOSS,INDUCTOR}} = R_{\text{DC}} \times (I_{\text{OUT}})^2$$

$R_{\text{DC}} = 12 \text{ m}\Omega$  is the assumed DC resistance of the inductor.

### Lifetime Estimation and Use Case Assumptions

The TPS62366x MTTF is computed with a standard Black equation with  $E_a = 1\text{eV}$  and  $n = 2$ . The operating conditions in these estimations assume example use cases that are characterized by an average output current of  $1.5 \text{ A} \leq I_{\text{OUT,AVE}} \leq 3.5 \text{ A}$  with a peak output current  $I_{\text{OUT,PEAK}} \leq 4 \text{ A}$ .  $V_{\text{OUT}}$  is fixed at  $V_{\text{OUT}} = 1.0 \text{ V}$  or  $1.2 \text{ V}$ . The board temperature is  $T_{\text{BOARD}} = 65^{\circ}\text{C}$  or  $85^{\circ}\text{C}$ . The computed lifetime plots as a function of  $V_{\text{IN}}$  and  $I_{\text{OUT,AVE}}$ .

### Results and Discussion

Figures 1-4 show the calculated TPS62366x lifetime as a function of  $(I_{\text{OUT,AVE}}, V_{\text{IN}})$  for fixed  $V_{\text{OUT}}$  and  $T_{\text{BOARD}}$ .

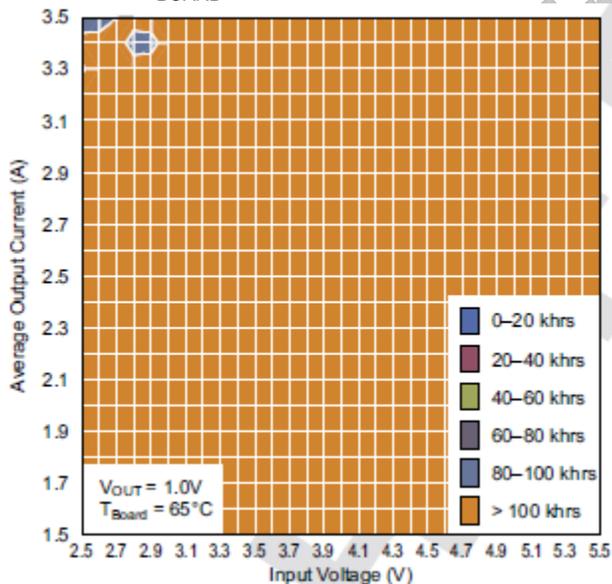


Figure 1. Lifetime for  $V_{\text{OUT}} = 1.0 \text{ V}$ ,  $T_{\text{BOARD}} = 65^{\circ}\text{C}$

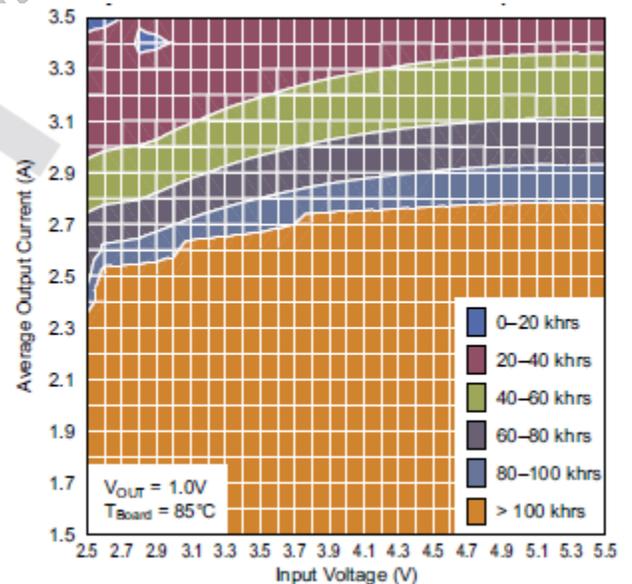


Figure 2. Lifetime for  $V_{\text{OUT}} = 1.0 \text{ V}$ ,  $T_{\text{BOARD}} = 85^{\circ}\text{C}$

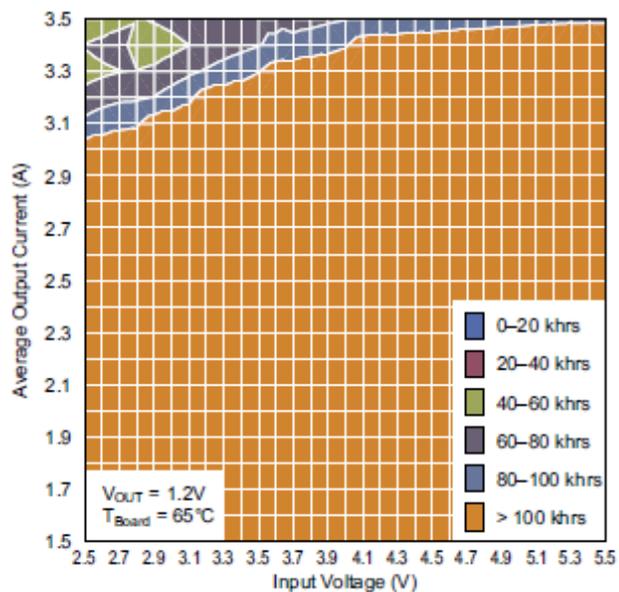


Figure 3. Lifetime for  $V_{OUT} = 1.2\text{ V}$ ,  $T_{BOARD} = 65^\circ\text{C}$

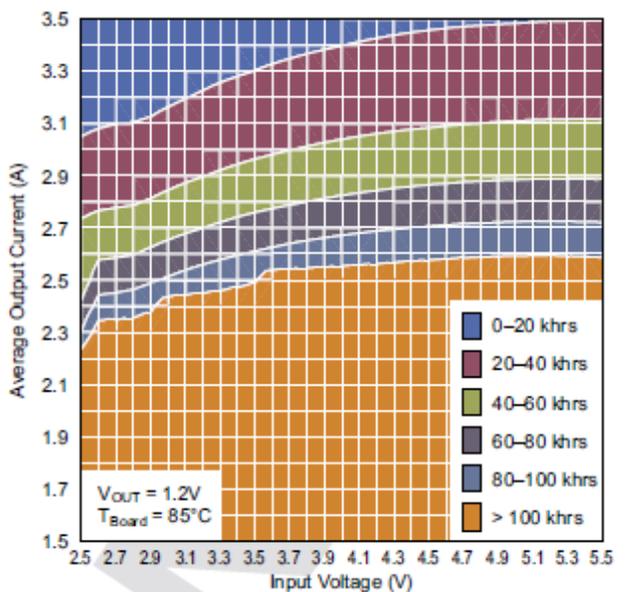


Figure 4. Lifetime for  $V_{OUT} = 1.2\text{ V}$ ,  $T_{BOARD} = 85^\circ\text{C}$

These results are summarized in a few key observations:

- For board temperatures up to  $T_{BOARD} = 85^\circ\text{C}$ , the electromigration-induced lifetime degradation is negligible for all use cases with  $I_{OUT,AVE} < 2.5\text{ A}$ .
- At the highest board temperature  $T_{BOARD} = 85^\circ\text{C}$  and large  $I_{OUT,AVE}$  currents, the influence of electromigration can be strongly attenuated by operating conditions outside of the largest  $V_{OUT}/V_{IN}$  operation duty cycles.
- At board temperature  $T_{BOARD} = 65^\circ\text{C}$ , the lifetime is only impacted at the most extreme use case conditions ( $I_{OUT,AVE} > 3\text{ A}$  together with larger  $V_{OUT}/V_{IN}$  duty cycles).

## PCB Layout Recommendations

Proper PCB layout with focus on thermal performance results in smaller junction-to-ambient ( $\theta_{JA}$ ) and junction-to-board ( $\theta_{JB}$ ) thermal resistances, thereby reducing the device junction temperature,  $T_J$  for a given dissipated power and board temperature. Wide power traces can sink dissipated heat. This is improved even further on multi-layer PCB designs with vias to different layers. In addition, many system-dependent issues such as thermal coupling, airflow, added heat sinks and convection surfaces, and the presence of other heat-generating components, affect the power dissipation capabilities of a given device.

## Conclusion

The potential impact of electromigration on the reliability of TI's TPS62366x (4A peak output current) DCDC converter family was calculated using Black's equation fed by experimentally measured efficiency and thermal parameters.

Electromigration-induced reliability damage was found to be very low outside of the extreme corners of continuous operating conditions ( $T_{\text{BOARD}} = 85^{\circ}\text{C}$  with  $I_{\text{OUT,AVE}} > 2.5\text{ A}$  and large  $V_{\text{OUT}}/V_{\text{IN}}$  duty cycles).

PCB layout recommendations were issued, improving thermal dissipation performance and reducing the junction temperature,  $T_J$ .

## References

1. JR Black, *Proceedings of the IEEE* **57**, 1587 (1969)
2. JR Black, *IEEE Transactions on Electron Devices* **16**, 338 (1969)
3. FY Ouyang, CL Kao, *J. Appl. Phys.* **110**, 123525 (2011)
4. MHR Jen, LC Liu, YS Lai, *J. Appl. Phys.* **107**, 093526 (2010)
5. SW Liang, YW Chang, C Chen, *Appl. Phys. Lett.* **88**, 172108 (2006)
6. CY Liu, Lin Ke, YC Chuang, SJ Wang, *J. Appl. Phys.* **100**, 083702 (2006)
7. JW Nah, JO Suh, KN Tu, *J. Appl. Phys.* **98**, 013715 (2005)
8. JW Nah, JH Kim, HM Lee, KW Paik, *Acta Materialia* **52**, 129 (2004)
9. KN Tu, *J. Appl. Phys.* **94**, 5451 (2003)
10. JD Wu, PJ Zheng, Kelly Lee, CT Chiu, JJ Lee, *Proceedings 52nd Electronic Components and Technology Conference*, IEEE, 452 (2002)
11. ET Ogawa, KD Lee, VA Blaschke, PS Ho, *IEEE Transactions on Reliability*, 51, 403 (2002)
12. TY Lee, KN Tu, DR Frear, *J. Appl. Phys.* **90**, 4502 (2001)
13. TY Lee, KN Tu, SM Kuo, DR Frear, *J. Appl. Phys.* **89**, 3189 (2001)

## IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46C and to discontinue any product or service per JESD48B. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have **not** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

### Products

Audio	<a href="http://www.ti.com/audio">www.ti.com/audio</a>
Amplifiers	<a href="http://amplifier.ti.com">amplifier.ti.com</a>
Data Converters	<a href="http://dataconverter.ti.com">dataconverter.ti.com</a>
DLP® Products	<a href="http://www.dlp.com">www.dlp.com</a>
DSP	<a href="http://dsp.ti.com">dsp.ti.com</a>
Clocks and Timers	<a href="http://www.ti.com/clocks">www.ti.com/clocks</a>
Interface	<a href="http://interface.ti.com">interface.ti.com</a>
Logic	<a href="http://logic.ti.com">logic.ti.com</a>
Power Mgmt	<a href="http://power.ti.com">power.ti.com</a>
Microcontrollers	<a href="http://microcontroller.ti.com">microcontroller.ti.com</a>
RFID	<a href="http://www.ti-rfid.com">www.ti-rfid.com</a>
OMAP Mobile Processors	<a href="http://www.ti.com/omap">www.ti.com/omap</a>
Wireless Connectivity	<a href="http://www.ti.com/wirelessconnectivity">www.ti.com/wirelessconnectivity</a>

### Applications

Automotive and Transportation	<a href="http://www.ti.com/automotive">www.ti.com/automotive</a>
Communications and Telecom	<a href="http://www.ti.com/communications">www.ti.com/communications</a>
Computers and Peripherals	<a href="http://www.ti.com/computers">www.ti.com/computers</a>
Consumer Electronics	<a href="http://www.ti.com/consumer-apps">www.ti.com/consumer-apps</a>
Energy and Lighting	<a href="http://www.ti.com/energy">www.ti.com/energy</a>
Industrial	<a href="http://www.ti.com/industrial">www.ti.com/industrial</a>
Medical	<a href="http://www.ti.com/medical">www.ti.com/medical</a>
Security	<a href="http://www.ti.com/security">www.ti.com/security</a>
Space, Avionics and Defense	<a href="http://www.ti.com/space-avionics-defense">www.ti.com/space-avionics-defense</a>
Video and Imaging	<a href="http://www.ti.com/video">www.ti.com/video</a>

**TI E2E Community** [e2e.ti.com](http://e2e.ti.com)